

Dual General Purpose Transistor

PNP Dual

BC858CDXV6T1, BC858CDXV6T5

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-563 which is designed for low power surface mount applications.

Features

• These are Pb-Free Devices

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	-30	V
Collector-Base Voltage	V_{CBO}	-30	V
Emitter-Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	Ic	-100	mAdc

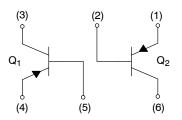
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation, (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	357 2.9	mW mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	350	°C/W
Characteristic (Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation, (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	500 4.0	mW mW/°C
Thermal Resistance Junction-to-Ambient (Note 1)	$R_{\theta JA}$	250	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

1

1. FR-4 @ Minimum Pad





SOT-563 CASE 463A PLASTIC

MARKING DIAGRAMS



3L = Device CodeM = Date CodePb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BC858CDXV6T1G	SOT-563 (Pb-Free)	4000 / Tape & Reel

DISCONTINUED (Note 1)

	,	
BC858CDXV6T1	SOT-563	4000 / Tape & Reel
BC858CDXV6T5		8000 / Tape &
BC858CDXV6T5G	SOT-563 (Pb-Free)	Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

 DISCONTINUED: These devices are not recommended for new design. Please contact your onsemi representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.

BC858CDXV6T1, BC858CDXV6T5

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	•		•	•	
Collector-Emitter Breakdown Voltage (I _C = -10 mA)	V _{(BR)CEO}	-30	_	-	V
Collector - Emitter Breakdown Voltage ($I_C = -10 \mu A, V_{EB} = 0$)	V _(BR) CES	-30	_	_	V
Collector-Base Breakdown Voltage ($I_C = -10 \mu A$)	V _{(BR)CBO}	-30	_	-	V
Emitter -Base Breakdown Voltage (I _E = -1.0 μA)	V _{(BR)EBO}	-5.0	_	-	V
Collector Cutoff Current ($V_{CB} = -30 \text{ V}$) ($V_{CB} = -30 \text{ V}$, $T_A = 150 ^{\circ}\text{C}$)	I _{CBO}	- -	_ _	-15 -4.0	nA μA
ON CHARACTERISTICS			•		
DC Current Gain $ \begin{array}{l} \text{(I}_C = -10~\mu\text{A, V}_{CE} = -5.0~\text{V}) \\ \text{(I}_C = -2.0~\text{mA, V}_{CE} = -5.0~\text{V}) \end{array} $	h _{FE}	- 420	270 520	_ 800	-
Collector – Emitter Saturation Voltage ($I_C = -10 \text{ mA}, I_B = -0.5 \text{ mA}$) ($I_C = -100 \text{ mA}, I_B = -5.0 \text{ mA}$)	V _{CE(sat)}	- -	_ _	-0.3 -0.65	V
Base – Emitter Saturation Voltage $ \begin{array}{l} \text{(I}_{\text{C}} = -10 \text{ mA, I}_{\text{B}} = -0.5 \text{ mA)} \\ \text{(I}_{\text{C}} = -100 \text{ mA, I}_{\text{B}} = -5.0 \text{ mA)} \end{array} $	V _{BE(sat)}	_ _	-0.7 -0.9	- -	V
Base – Emitter On Voltage ($I_C = -2.0$ mA, $V_{CE} = -5.0$ V) ($I_C = -10$ mA, $V_{CE} = -5.0$ V)	V _{BE(on)}	-0.6 -	_ _	-0.75 -0.82	V
SMALL-SIGNAL CHARACTERISTICS	•		•	•	
Current-Gain – Bandwidth Product ($I_C = -10$ mA, $V_{CE} = -5.0$ Vdc, $f = 100$ MHz)	f _T	100	-	-	MHz
Output Capacitance ($V_{CB} = -10 \text{ V}, f = 1.0 \text{ MHz}$)	C _{ob}	-	_	4.5	pF
Noise Figure $ \begin{array}{l} \text{(I}_{C}=-0.2 \text{ mA, V}_{CE}=-5.0 \text{ Vdc, R}_{S}=2.0 \text{ k}\Omega, \\ \text{f}=1.0 \text{ kHz, BW}=200 \text{ Hz)} \end{array} $	NF	-	_	10	dB

BC858CDXV6T1, BC858CDXV6T5

TYPICAL CHARACTERISTICS

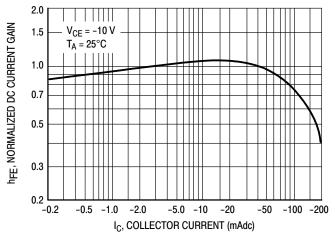


Figure 1. Normalized DC Current Gain

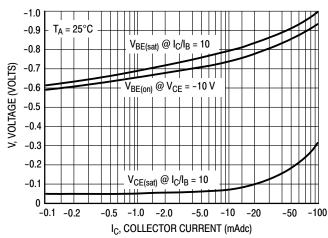


Figure 2. "Saturation" and "On" Voltages

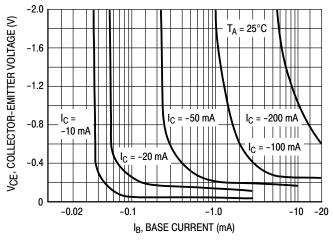


Figure 3. Collector Saturation Region

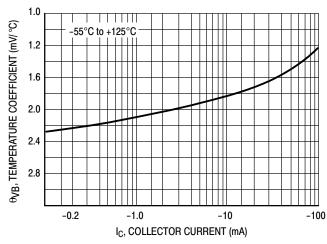


Figure 4. Base-Emitter Temperature Coefficient

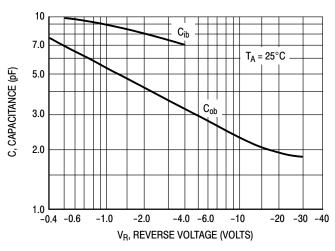


Figure 5. Capacitances

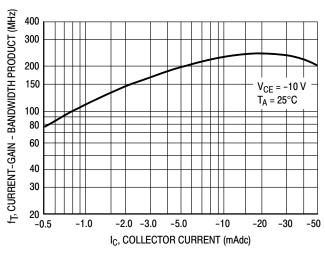


Figure 6. Current-Gain - Bandwidth Product



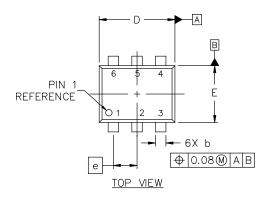


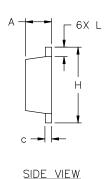
SOT-563-6 1.60x1.20x0.55, 0.50P CASE 463A **ISSUE J**

DATE 15 FEB 2024

NOTES:

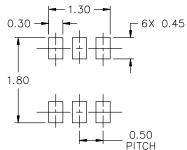
- 1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.





DIM	MILLIMETERS		
ויונע	MIN.	N□M.	MAX.
Α	0.50	0.55	0.60
b	0.17	0.22	0.27
С	0.08	0.13	0.18
D	1,50	1.60	1.70
Е	1.10	1,20	1.30
е	0.50 BSC		
Н	1.50	1.60	1.70
L	0.10	0.20	0.30

MILL IMETERS



STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1	STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1	STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE 1
6. COLLECTOR 1	6. COLLECTOR 1	6. ANDDE/ANDDE 1

RECOMMENDED	MOUNTING	FOOTPRINT*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

0714 5 7	0714 5 0	07.4 5 0
STYLE 7:	STYLE 8:	STYLE 9:
PIN 1. CATHODE	PIN 1. DRAIN	PIN 1. SOURCE 1
2. ANODE	2. DRAIN	2. GATE 1
3. CATHODE	3. GATE	3. DRAIN 2
4. CATHODE	4. SOURCE	4. SOURCE 2
5. ANDDE	5. DRAIN	5. GATE 2
6. CATH□DE	6. DRAIN	6. DRAIN 1

PIN 1. EMITTER 2

STYLE 11:

3. ANDDE

4. ANDDE 5. CATHODE

6. CATHODE

STYLE 5: PIN 1. CATHODE 2. CATHODE

GENERIC MARKING DIAGRAM*



XX = Specific Device Code M = Month Code = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

2. N/C	2.	BASE 2
3. CATHODE	2 3.	COLLECTOR
4. AN□DE 2	4.	EMITTER 1
5. N/C	5.	BASE 1
6. AN□DE 1	6.	COLLECTOR

STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR

3. BASE

STYLE 10:

PIN 1. CATHODE 1

4. EMITTER
5. COLLECTOR
6. COLLECTOR

1 Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking. 2

STYLE 6: PIN 1. CATHODE 2. ANODE

3. CATHODE

4. CATHODE 5. CATHODE

CATHODE

DOCUMENT NUMBER:	98AON11126D Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOT-563-6 1.60x1.20x0.55	5, 0.50P	PAGE 1 OF 1

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